CGY1041

1 GHz, 21 dB gain GaAs push-pull amplifier Rev. 1 — 10 February 2011

Product data sheet

Product profile 1.

1.1 General description

Hybrid amplifier module in a SOT115J package, operating at a supply voltage of 24 V Direct Current (DC), employing Heterojunction Field Effect Transistor (HFET) GaAs dies.

1.2 Features and benefits

- Excellent linearity, stability and reliability
- Extremely low noise
- Excellent return loss properties
- Rugged construction
- Unconditionally stable
- Thermally optimized design
- Superior levels of ESD protection
- Compliant to Directive 2002/95/EC, regarding Restriction of Hazardous Substances (RoHS)
- Integrated ring wave surge protection
- Power gain is specified for both 870 MHz and 1003 MHz bandwidth

1.3 Applications

CATV systems operating in the 40 MHz to 1003 MHz frequency range

1.4 Quick reference data

Quick reference data

Bandwidth 40 MHz to 1003 MHz; $V_B = 24 \text{ V (DC)}$; $Z_S = Z_L = 75 \Omega$; $T_{mb} = 35 ^{\circ}\text{C}$; unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|----------------------------|-------------------------|--------------|-------|------|------|
| G_p | power gain | f = 45 MHz | 19.0 | 20.0 | 21.0 | dB |
| | | f = 870 MHz | 20.4 | 21.4 | 22.4 | dB |
| | | f = 1003 MHz | 21.0 | 21.75 | 22.5 | dB |
| СТВ | composite triple beat | $V_o = 44 \text{ dBmV}$ | <u>[1]</u> _ | -62 | - | dBc |
| CCN | carrier-to-composite noise | $V_o = 44 \text{ dBmV}$ | <u>[1]</u> _ | 63 | - | dBc |
| I _{tot} | total current | | <u>[2]</u> _ | 265 | 280 | mA |

^{[1] 79} NTSC channels [f = 55.25 MHz to 547.25 MHz] + 75 digital channels [f = 547.25 MHz to 1003 MHz] (-6 dB offset); flat output level.

[2] Direct Current (DC).



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2. Pinning information

Table 2. Pinning

| Pin | Description | Simplified outline Graphic symbol |
|------|-----------------|-----------------------------------|
| 1 | input | |
| 2, 3 | common | 1 3 5 7 9 |
| 5 | +V _B | |
| 7, 8 | common | 23 7 8 |
| 9 | output | sym095 |
| | | • |

3. Ordering information

Table 3. Ordering information

| Type number | Package | | | | |
|-------------|---------|---|---------|--|--|
| | Name | Description | Version | | |
| CGY1041 | - | rectangular single-ended package; aluminium flange; 2 vertical mounting holes; $2 \times 6-32$ UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads | SOT115J | | |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | | Min | Max | Unit |
|------------------|---------------------------------|---|------------|-----|------|------|
| V_{B} | supply voltage | | | - | 30 | V |
| $V_{i(RF)}$ | RF input voltage | single tone | | - | 75 | dBmV |
| V _{ESD} | electrostatic discharge voltage | Human Body Model (HBM); According JEDEC standard 22-A114E | <u>[1]</u> | - | 2000 | V |
| | | Biased; According IEC61000-4-2 | | - | 2000 | V |
| T _{stg} | storage temperature | | | -40 | +100 | °C |
| T_{mb} | mounting base temperature | | | -20 | +100 | °C |

^[1] The value of 2000 V corresponds to a class 2 classification.

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5. Characteristics

Table 5. Characteristics

Bandwidth 40 MHz to 1003 MHz; $V_B = 24 \text{ V (DC)}$; $Z_S = Z_L = 75 \Omega$; $T_{mb} = 35 \text{ °C}$; unless otherwise specified.

| Symbol | Parameter | Conditions | | Min | Тур | Max | Unit |
|------------------|-----------------------------------|-------------------------|------------|------|------------|------|------|
| Gp | power gain | f = 45 MHz | | 19.0 | 20.0 | 21.0 | dB |
| | | f = 870 MHz | | 20.4 | 21.4 | 22.4 | dB |
| | | f = 1003 MHz | | 21.0 | 21.75 | 22.5 | dB |
| SL _{sl} | slope straight line | f = 45 MHz to 1003 MHz | [1] | 1.2 | 1.95 | 2.7 | dB |
| FL | flatness of frequency response | f = 45 MHz to 1003 MHz | [2] | - | - | 0.9 | dB |
| RL_{in} | input return loss | f = 45 MHz to 200 MHz | | 20 | - | - | dB |
| | | f = 200 MHz to 550 MHz | | 19 | - | - | dB |
| | | f = 550 MHz to 870 MHz | | 19 | - | - | dB |
| | | f = 870 MHz to 914 MHz | | 19 | - | - | dB |
| | | f = 914 MHz to 1003 MHz | | 16 | - | - | dB |
| RLout | output return loss | f = 45 MHz to 200 MHz | | 18 | - | - | dB |
| | | f = 200 MHz to 550 MHz | | 18 | - | - | dB |
| | | f = 550 MHz to 870 MHz | | 18 | - | - | dB |
| | | f = 870 MHz to 914 MHz | | 18 | - | - | dB |
| | | f = 914 MHz to 1003 MHz | | 16 | - | - | dB |
| NF | noise figure | f = 50 MHz to 870 MHz | | - | 3.6 | 4.0 | dB |
| | | f = 870 MHz to 1003 MHz | | - | 4.3 | 4.9 | dB |
| I _{tot} | total current | | [3] | - | 265 | 280 | mA |
| 79 NTSC | channels + 75 digital channels | | | | | | |
| СТВ | composite triple beat | $V_0 = 44 \text{ dBmV}$ | [4] | - | -62 | - | dBc |
| CSO | composite second-order distortion | $V_0 = 44 \text{ dBmV}$ | [4] | - | -64 | - | dBc |
| Xmod | cross modulation | $V_0 = 44 \text{ dBmV}$ | [4] | - | -58 | - | dB |
| CCN | carrier-to-composite noise | $V_0 = 44 \text{ dBmV}$ | [4] | - | 63 | - | dBc |
| 79 NTSC | channels | | | | | | |
| СТВ | composite triple beat | $V_0 = 44 \text{ dBmV}$ | <u>[5]</u> | - | - | -62 | dBc |
| CSO | composite second-order distortion | $V_0 = 44 \text{ dBmV}$ | <u>[5]</u> | - | - | -62 | dBc |
| Xmod | cross modulation | $V_0 = 44 \text{ dBmV}$ | <u>[5]</u> | - | -58 | - | dB |
| 98 PAL 0 | hannels | | | | | | |
| СТВ | composite triple beat | $V_0 = 44 \text{ dBmV}$ | [6] | - | -68 | - | dBc |
| CSO | composite second-order distortion | $V_0 = 44 \text{ dBmV}$ | [6] | - | -66 | - | dBc |
| Xmod | cross modulation | $V_0 = 44 \text{ dBmV}$ | <u>[6]</u> | - | -58 | - | dB |
| | | | | | | | |

^[1] G_p at 1003 MHz minus G_p at 45 MHz.

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^[2] Flatness is defined as maximum deviation to straight line.

www[3] at Direct Current (DC).

^{[4] 79} NTSC channels [f = 55.25 MHz to 547.25 MHz] + 75 digital channels [f = 547.25 MHz to 1003 MHz] (-6 dB offset); flat output level.

^{[5] 79} NTSC channels [f = 55.25 MHz to 550 MHz]; flat output level.

^{[6] 98} PAL channels [f = 49.75 MHz to 847.25 MHz]; flat output level.

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6. Package outline

Rectangular single-ended package; aluminium flange; 2 vertical mounting holes; 2 x 6-32 UNC and 2 extra horizontal mounting holes; 7 gold-plated in-line leads

SOT115J

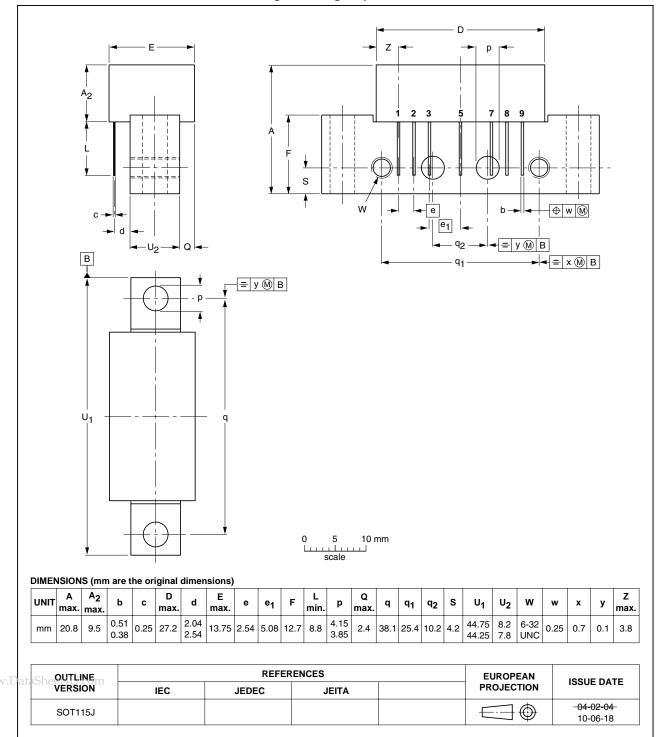


Fig 1. Package outline SOT115J

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7. Abbreviations

Table 6. Abbreviations

| Acronym | Description |
|---------|--|
| CATV | Community Antenna TeleVision |
| ESD | ElectroStatic Discharge |
| GaAs | Gallium Arsenide |
| NTSC | National Television Standard Committee |
| PAL | Phase Alternating Line |
| RF | Radio Frequency |
| UNC | UNified Coarse |

8. Revision history

Table 7. Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|-------------|--------------|--------------------|---------------|------------|
| CGY1041 v.1 | 20110210 | Product data sheet | - | - |

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9. Legal information

9.1 Data sheet status

| Document status[1][2] | Product status[3] | Definition |
|--------------------------------|-------------------|---|
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